## 10/586807 IAP11 Rec'd PCT/PTO 21 JUL 2006

## INFORMATION DISCLOSURE STATEMENT TRANSMITTAL

## To Commissioner For Patents

Examiner

Signature

Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.

Application Number	
Filing Date	
First Named Inventor	SHANNON, JOHN M.
Group Art Unit	
Examiner Name	
Atty. Docket Number	GB04 0023 US1

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				Atty. Docket Number	GB04 0023 US1				
			U.S. PAT	ENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number NoKind Code <sup>2</sup> ( <i>if known</i> )	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document		Pages, Columns Lines, Where Relevar Passages or Relevant Figures Appear			
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Examiner Initials*	Cite No.1	Document Number (ctry <sup>3</sup> -no. <sup>4</sup> -kind <sup>5</sup> , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document		Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear	T⁵		
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		N	ON-PATENT L	TERATURE DOCUMEN	ITS		5.5		
	ter   Cite   Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, se								
	1	GADELRAB S. M.: "THE SOURCE-GATED AMORPHOUS SILICON PHOTO-TRANSISTOR"; IEEE ELECTRON DEVICES VOL. 44 NO. 10; OCT. 1997. PP 1789-1794.  SHANNON J. M. ET AL.: "SOURCE-GATED THIN-FILM TRANSISTORS"; IEEE ELECTRON DEVICE LETTERS VOL. 24 NO. 6; JUNE 2003. PP 405-407.							
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<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> See attached Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English language Translation is attached.